

# PJQ2566A

## 60V N-Channel Enhancement Mode MOSFET

<b>Voltage</b>	<b>60 V</b>	<b>Current</b>	<b>20 A</b>
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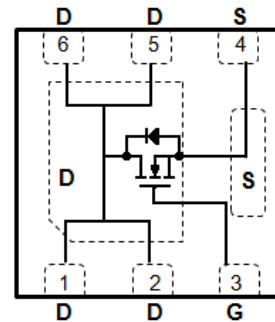
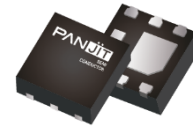
### Features

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@10A<14m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@6A<21m\Omega$
- Excellent FOM
- Logic Level Drive
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : DFN2020B-6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0086 grams

DFN2020B-6L



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	60	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	
Continuous Drain Current <sup>(Note 3)</sup>	$T_C=25^\circ C$	$I_D$	20	A
	$T_C=100^\circ C$		12.7	
Pulsed Drain Current <sup>(Note 1)</sup>	$T_C=25^\circ C$	$I_{DM}$	80	
Power Dissipation	$T_C=25^\circ C$	$P_D$	9.6	W
	$T_C=100^\circ C$		3.8	
Continuous Drain Current <sup>(Note 4)</sup>	$T_A=25^\circ C$	$I_D$	8.4	A
	$T_A=70^\circ C$		6.7	
Power Dissipation	$T_A=25^\circ C$	$P_D$	1.7	W
	$T_A=70^\circ C$		1.1	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ C$
Thermal Resistance <sup>(Note 4)</sup>	Junction to Case	$R_{\theta JC}$	13	$^\circ C/W$
	Junction to Ambient	$R_{\theta JA}$	75	

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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.4	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	11.2	14	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A	-	16.3	21	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>Dynamic</b> (Note 6)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =30V, I <sub>D</sub> =10A, V <sub>GS</sub> =10V (Note 2,3)	-	16.7	22	nC
Gate-Source Charge	Q <sub>gs</sub>		-	3.3	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	4	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V, f=1MHz	-	834	1168	pF
Output Capacitance	C <sub>oss</sub>		-	323	485	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	18	-	
Gate resistance	R <sub>g</sub>	f=1MHz	-	1.3	-	Ω
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DS</sub> =30V, I <sub>D</sub> =10A, V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω (Note 2,3)	-	7	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	20	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	17	-	
Turn-Off Fall Time	t <sub>f</sub>		-	16	-	
<b>Drain-Source Diode</b>						
Diode Forward Current	I <sub>S</sub>	T <sub>C</sub> =25°C	-	-	20	A
Pulsed Diode Forward Current	I <sub>SM</sub>		-	-	80	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =10A, V <sub>GS</sub> =0V	-	0.85	1.3	V
Reverse Recovery Time	T <sub>rr</sub>	V <sub>DD</sub> =30V, V <sub>GS</sub> =0V	-	40	-	ns
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>S</sub> =10A, dI <sub>S</sub> /dt=100A/us	-	21	-	nC

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Chip capability with an R<sub>θJC</sub>=13°C/W.
4. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz. square pad of copper.
5. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub>=25°C.
6. Guaranteed by design, not subject to production testing.

# PJQ2566A

## TYPICAL CHARACTERISTIC CURVES

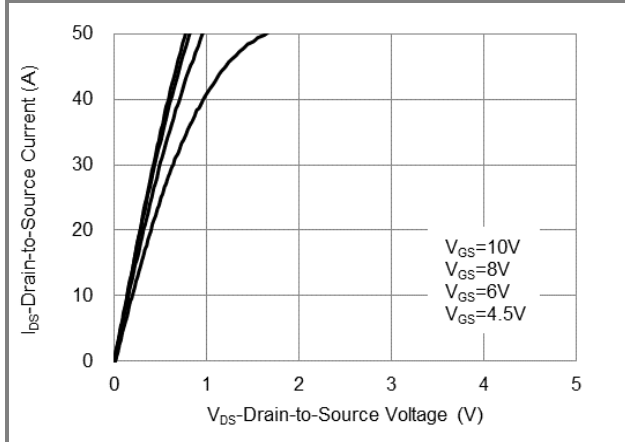


Fig.1 On-Region Characteristics

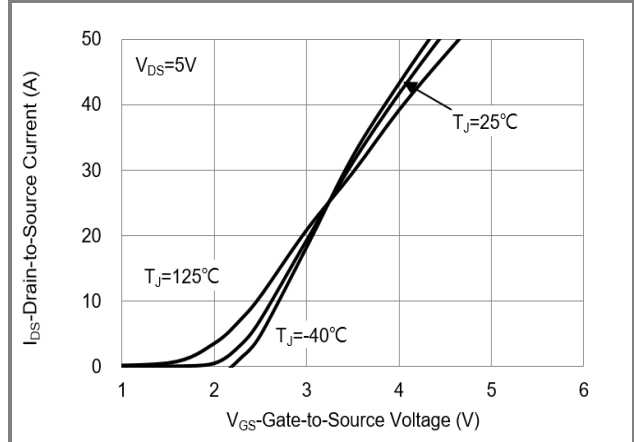


Fig.2 Transfer Characteristics

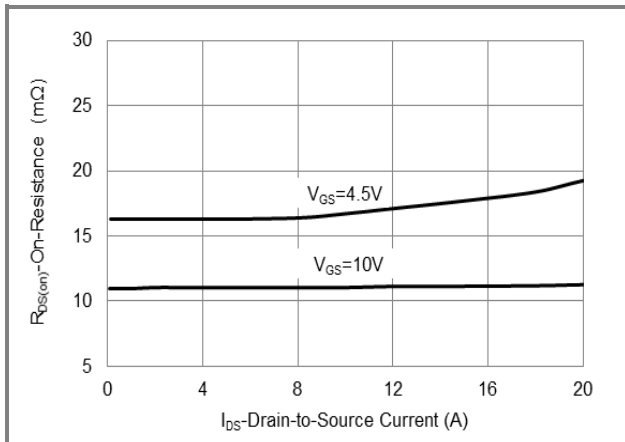


Fig.3 On-Resistance vs. Drain Current

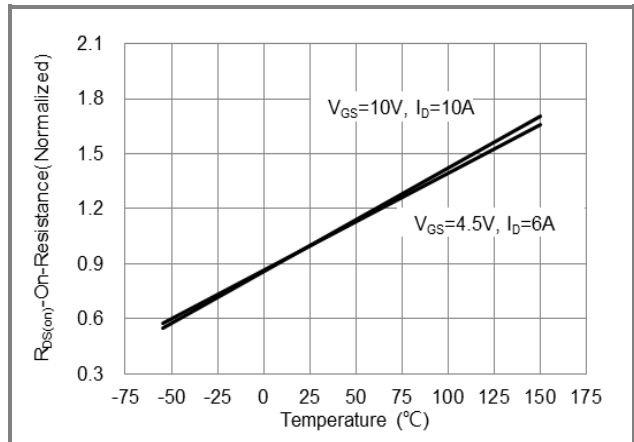


Fig.4 On-Resistance vs. Junction temperature

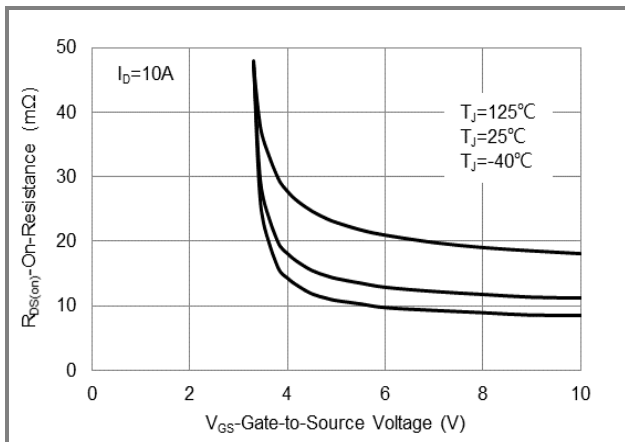


Fig.5 On-Resistance Variation with Vgs

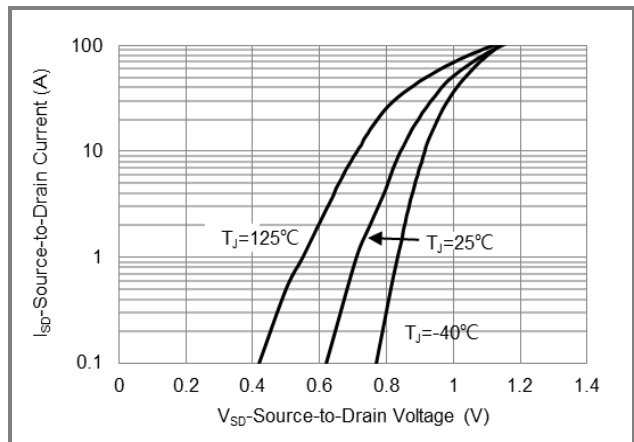


Fig.6 Source-Drain Diode Forward Voltage

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## TYPICAL CHARACTERISTIC CURVES

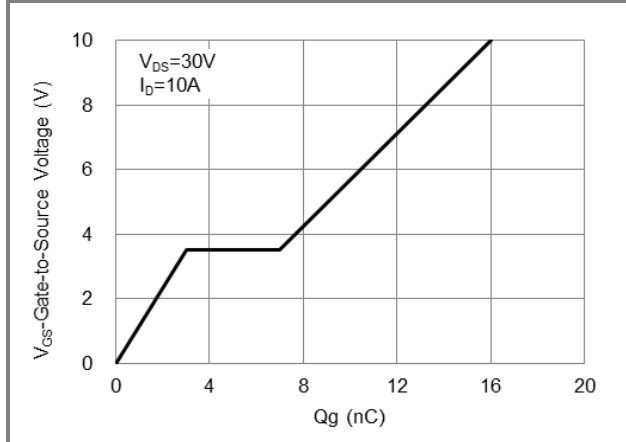


Fig.7 Gate-Charge Characteristics

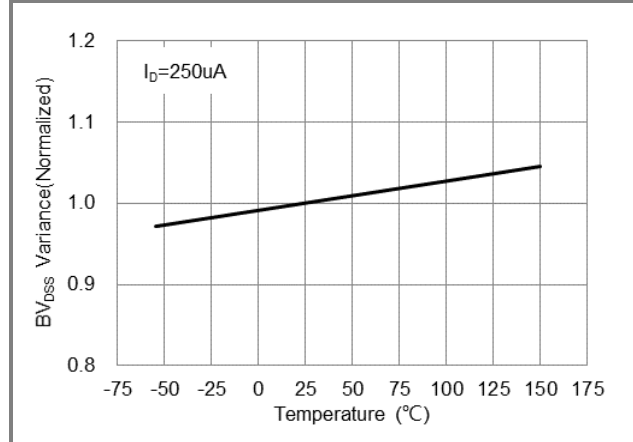


Fig.8 Breakdown Voltage Variation vs. Temperature

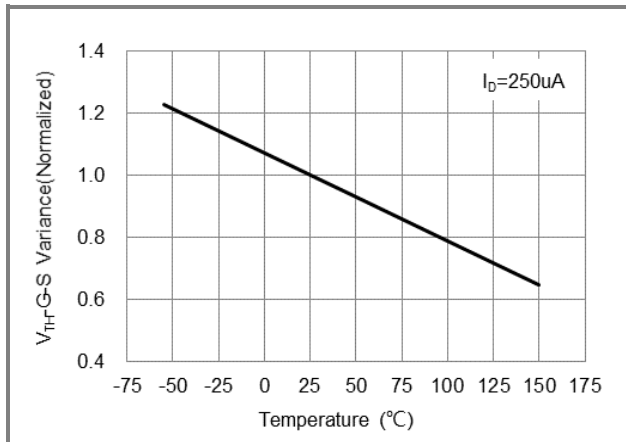


Fig.9 Threshold Voltage Variation with Temperature

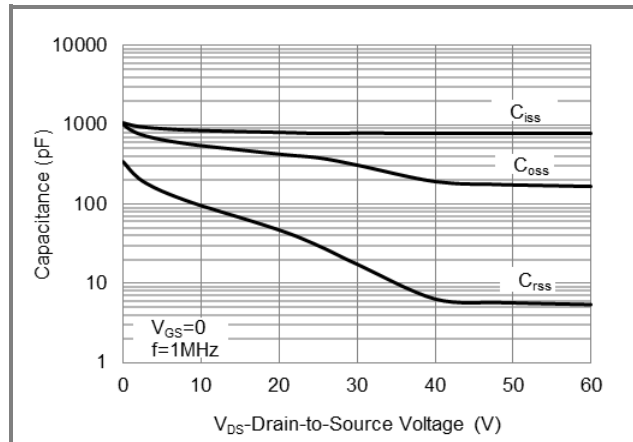


Fig.10 Capacitance vs. Drain-Source Voltage

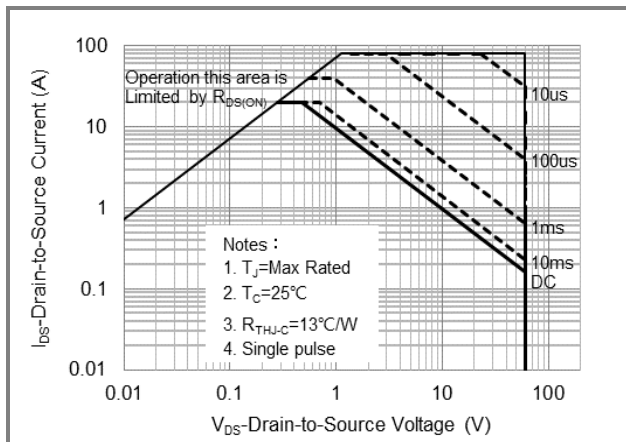


Fig.11 Maximum Safe Operating Area

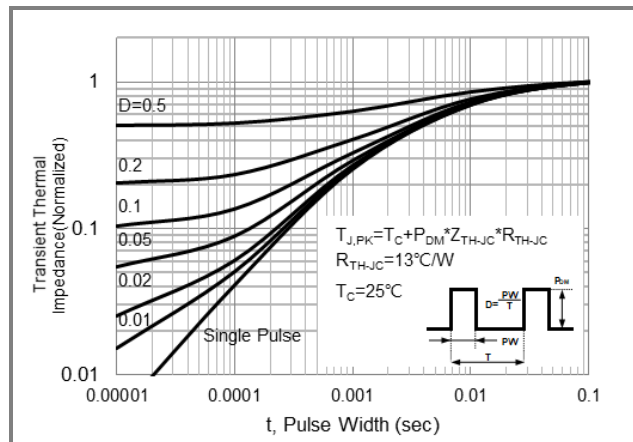


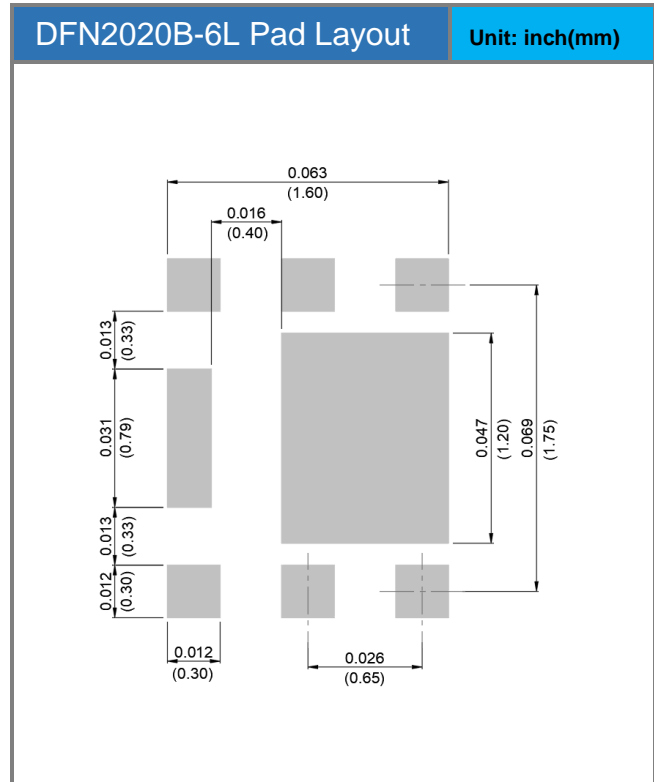
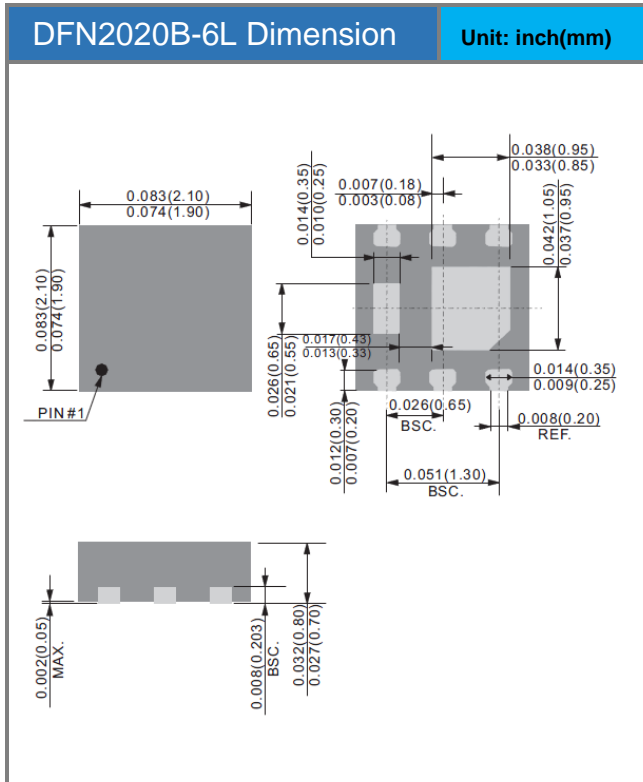
Fig.12 Normalized Transient Thermal Impedance

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## Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ2566A	DFN2020B-6L	3K pcs / 7" reel	566

## Packaging Information & Mounting Pad Layout



## PJQ2566A

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